Excellent Integrated System Limited

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

ON Semiconductor NSA5.0AT3G

For any questions, you can email us directly: sales@integrated-circuit.com

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



NSA5.0AT3G

400 Watt Peak Power Zener Transient Voltage Suppressor

Unidirectional

The NSA5.0AT3G is designed to protect voltage sensitive components from high voltage, high energy transients. It has excellent clamping capability, high surge capability, low zener impedance and a fast response time. The NSA5.0AT3G is ideally suited for use in communication systems, automotive, numerical controls, process controls, medical equipment, business machines, power supplies and many other industrial/consumer applications.

Features

- Peak Power 400 W @ 1 ms
- ESD Rating of Class 3 (> 16 kV) per Human Body Model
- ESD Rating IEC 61000-4-2 (> 30 kV)
- Response Time is Typically < 1 ns
- Flat Handling Surface for Accurate Placement
- Package Design for Top Slide or Bottom Circuit Board Mounting
- Low Profile Package
- Pb–Free Packages are Available

Mechanical Characteristics:

CASE: Void-free, transfer-molded plastic

FINISH: All external surfaces are corrosion resistant and leads are

readily solderable

MAXIMUM CASE TEMPERATURE FOR SOLDERING PURPOSES:

260°C for 10 Seconds

POLARITY: Cathode indicated by molded polarity notch or polarity

MOUNTING POSITION: Any



ON Semiconductor®

http://onsemi.com

PLASTIC SURFACE MOUNT ZENER OVERVOLTAGE TRANSIENT SUPPRESSOR **400 W PEAK POWER**





SMA CASE 403D **PLASTIC**

MARKING DIAGRAM



QA = Device Code = Assembly Location

= Year

= Work Week \\\\\\ = Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping [†]		
NSA5.0AT3G	SMA (Pb-Free)	5000/Tape & Reel		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

DEVICE MARKING INFORMATION

See specific marking information in the device marking column of the Electrical Characteristics table on page 2 of this data sheet.

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Datasheet of NSA5.0AT3G - TVS DIODE 5VWM 9.2VC SMA

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NSA5.0AT3G

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Power Dissipation (Note 1) @ T _L = 25°C, Pulse Width = 1 ms	P _{PK}	400	W
DC Power Dissipation @ T _L = 75°C Measured Zero Lead Length (Note 2) Derate Above 75°C Thermal Resistance from Junction to Lead	P _D	1.5 20 50	W mW/°C °C/W
DC Power Dissipation (Note 3) @ T _A = 25°C Derate Above 25°C Thermal Resistance from Junction to Ambient	P _D R _{θJA}	0.5 4.0 250	W mW/°C °C/W
Forward Surge Current (Note 4) @ T _A = 25°C	I _{FSM}	40	Α
Operating and Storage Temperature Range	T _J , T _{stg}	-65 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

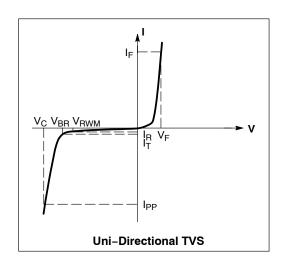
1. 10 X 1000 μs, non–repetitive.

- 2. 1" square copper pad, FR-4 board.
- 3. FR-4 board, using ON Semiconductor minimum recommended footprint, as shown in 403D case outline dimensions spec.
- 4. 1/2 sine wave (or equivalent square wave), PW = 8.3 ms, duty cycle = 4 pulses per minute maximum.

ELECTRICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Symbol	Symbol Parameter							
Cymbo.	T didiliotoi							
I _{PP}	Maximum Reverse Peak Pulse Current							
V _C Clamping Voltage @ I _{PP}								
V_{RWM}	Working Peak Reverse Voltage							
I _R	Maximum Reverse Leakage Current @ V _{RWM}							
V _{BR}	Breakdown Voltage @ I _T							
Ι _Τ	Test Current							
I _F	Forward Current							
V _F	Forward Voltage @ I _F							



ELECTRICAL CHARACTERISTICS

		V _{RWM}	I _R @	Breakdown Voltage				V _C @ I _{PP} (Note 7)		C Typ.	V _F @ I _F (Note 9)
	Device	(Note 5)	V _{RWM}	V _{BR} (Volts) (Note 6)		@ I _T	V _C	I _{PP}	(Note 8)	Max	
Device	Marking	Volts	μ Α	Min	Nom	Max	mA	Volts	Amps	pF	٧
NSA5.0AT3G	QA	5.0	400	6.4	6.7	7.0	10	9.2	43.5	2450	3.5

- A transient suppressor is normally selected according to the working peak reverse voltage (V_{RWM}), which should be equal to or greater than the DC or continuous peak operating voltage level.
- V_{BR} measured at pulse test current I_T at an ambient temperature of 25°C.
 Surge current waveform per Figure 2 and derate per Figure 3.
 Bias voltage = 0 V, F = 1.0 MHz, T_J = 25°C.

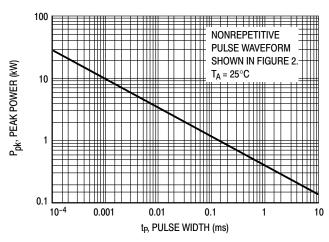
- 9. 1/2 sine wave or equivalent, PW = 8.3 ms, non-repetitive, I_F = 30 A.



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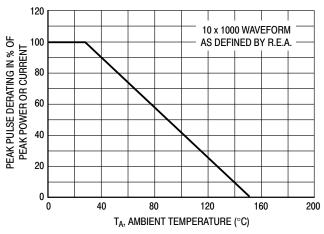
RATING AND TYPICAL CHARACTERISTIC CURVES



120 $T_A = 25^{\circ}C$ – ≤ 10 μs PW (ID) IS DEFINED AS THE lppm, PEAK PULSE CURRENT (%) 100 POINT WHERE THE PEAK CURRENT DECAYS TO 50% OF Ipp. 80 I_{ppm} 60 HALF VALUE - I_{DD}/2 40 10/1000 μs WAVEFORM AS DEFINED BY R.E.A. 20 ٥l 0 3 5 t, TIME (ms)

Figure 1. Pulse Rating Curve

Figure 2. Pulse Waveform



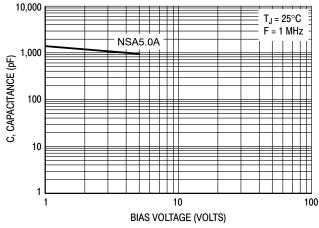


Figure 3. Pulse Derating Curve

Figure 4. Typical Junction Capacitance vs. Bias Voltage

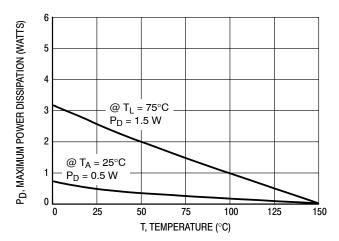


Figure 5. Steady State Power Derating



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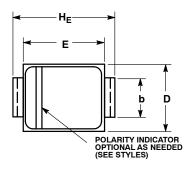
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PACKAGE DIMENSIONS

SMA CASE 403D-02 ISSUE E



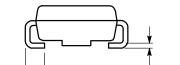
- NOTES:

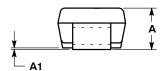
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: INCH.

 3. 403D-01 OBSOLETE, NEW STANDARD IS 403D-02.

	M	ILLIMETE	RS	INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	1.97	2.10	2.20	0.078	0.083	0.087	
A1	0.05	0.10	0.15	0.002	0.004	0.006	
b	1.27	1.45	1.63	0.050	0.057	0.064	
С	0.15	0.28	0.41	0.006	0.011	0.016	
D	2.29	2.60	2.92	0.090	0.103	0.115	
E	4.06	4.32	4.57	0.160	0.170	0.180	
HE	4.83	5.21	5.59	0.190	0.205	0.220	
L	0.76	1.14	1.52	0.030	0.045	0.060	

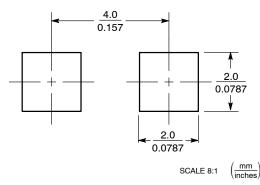




STYLE 1: PIN 1. CATHODE (POLARITY BAND)

2. ANODE

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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